

# **NCE N-Channel Super Trench II Power MOSFET**

### **Description**

The NCEP0230D uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

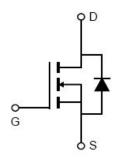
#### **General Features**

- V<sub>DS</sub> =200V,I<sub>D</sub> =30A
  R<sub>DS(ON)</sub>=40mΩ (typical) @ V<sub>GS</sub>=10V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

TO-263





**Schematic Diagram** 

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP0230D	NCEP0230D	TO-263-2L	-	-	-

### Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	200	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	30	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	21	Α
Pulsed Drain Current	I <sub>DM</sub>	100	Α
Maximum Power Dissipation	P <sub>D</sub>	135	W
Derating factor		0.9	W/°C
Single pulse avalanche energy (Note1)	E <sub>AS</sub>	320	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	$^{\circ}$

#### **Thermal Characteristic**

Thermal Résistance, Junction-to-Case	Rejc	1.11	°C/W	I
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# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics				•		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	200	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}$ = $V_{GS}$ , $I_{D}$ = $250\mu A$	2.5	3.5	4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	40	45	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	15	-	-	S
Dynamic Characteristics						
Input Capacitance	C <sub>lss</sub>	.,	-	1635		PF
Output Capacitance	Coss	$V_{DS}=100V, V_{GS}=0V,$	-	128		PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	3		PF
Switching Characteristics (Note 2)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	7	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =100V, $R_L$ =5 $\Omega$	-	9	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$	-	25	-	nS
Turn-Off Fall Time	tf		-	5	-	nS
Total Gate Charge	Qg	V 400V/I 00A	-	25	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =100V,I <sub>D</sub> =20A,	-	10.6	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	6	-	nC
Drain-Source Diode Characteristics	'		•			
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	30	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> = I <sub>S</sub>	-	45	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	160	-	nC

#### Notes:

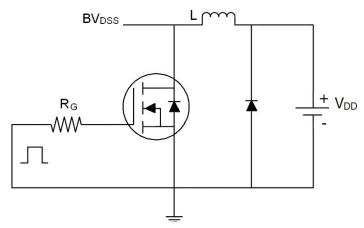
<sup>1.</sup> EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=50V,VG=10V,L=0.5mH,Rg=25 $\Omega$ 

<sup>2.</sup> Guaranteed by design, not subject to production

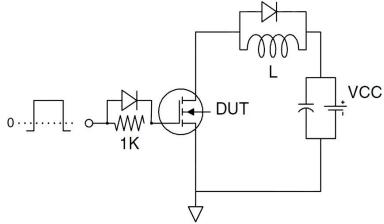
<sup>3.</sup> These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsin k, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.

### **Test Circuit**

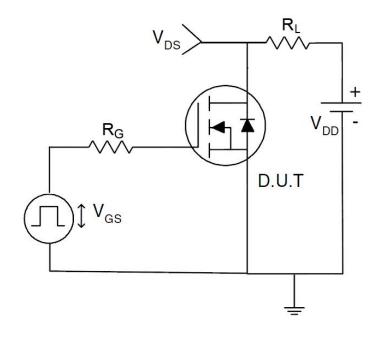
# 1) E<sub>AS</sub> test Circuit



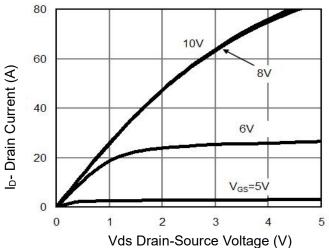
# 2) Gate charge test Circuit



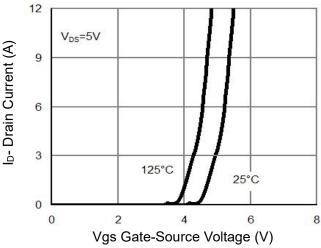
# 3) Switch Time Test Circuit



# **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

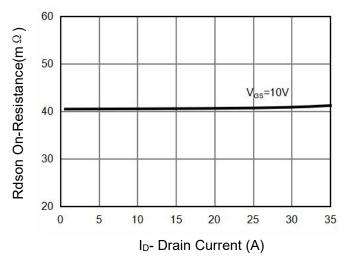
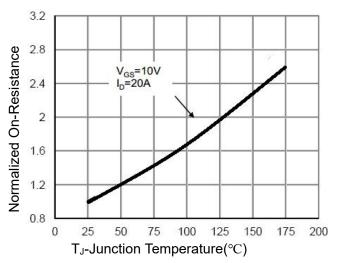


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

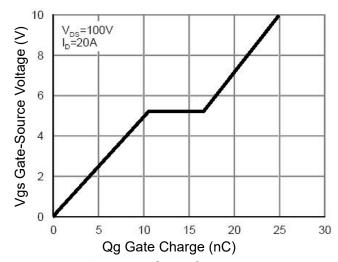


Figure 5 Gate Charge

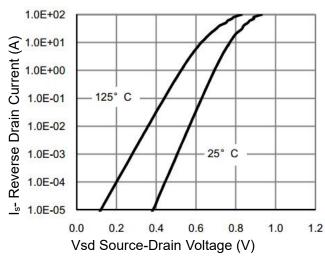
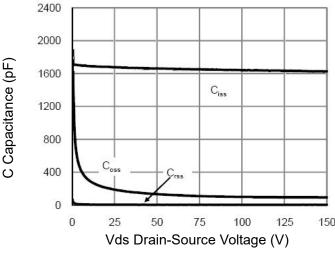


Figure 6 Source- Drain Diode Forward



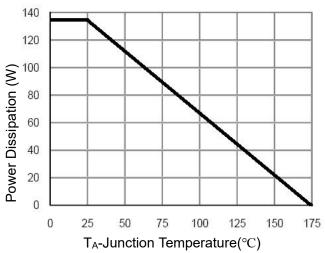
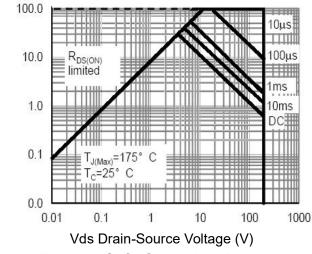


Figure 7 Capacitance vs Vds

Figure 9 Power De-rating



Ip- Drain Current (A)

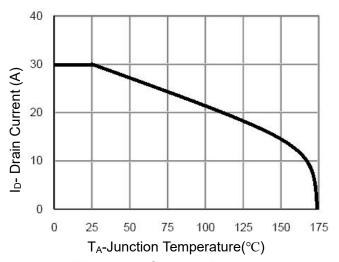
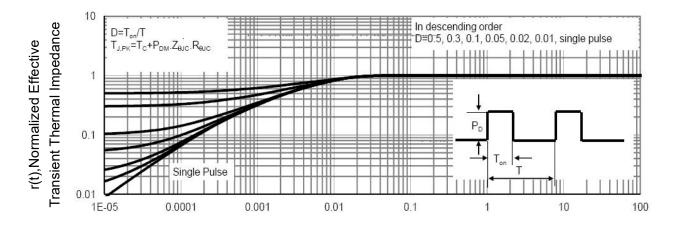


Figure 8 Safe Operation Area(Note 3)

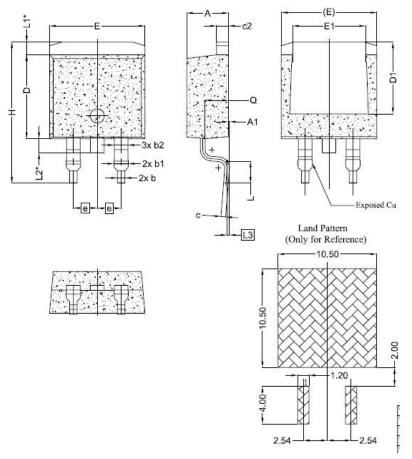
Figure 10 Current De-rating



Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

# **TO-263-2L Package Information**



SYMBOL	DIMENSIONS				
	MIN.	NOM.	MAX.		
Α	4.24	4.44	4.64		
A1	0.00	0.10	0.25		
b	0,70	0.80	0.90		
b1	1.20	1,55	1.75		
b2	1,20	1,45	1,70		
С	0.40	0.50	0.60		
c2	1,15	1,27	1,40		
D	8.82	8.92	9.02		
D1	6.86	7.65			
E	9.96	10,16	10,36		
E1	6,89	7.77	7.89		
е		2,54 BSC			
Н	14,61	15,00	15,88		
L	1.78	2.32	2.79		
L1	1.36 REF.				
L2	1.50 REF.				
L3	0.25 BSC				
Q	2.30	2.48	2,70		

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